E-Beam Welded Shunt 8518

EBW8518

Features

- Electron-beam welded technology
- Low thermal EMF
- Low measurement inductance
- Robust copper terminals for busbar mounting
- AEC-Q200 qualified

All parts are Pb-free and comply with EU Directive 2011/65/EU amended by (EU) 2015/863 (RoHS3)

Electrical Data

		EBW8518			
Power rating at 70°C	W	36			
Resistance range	μΩ	50 to 250			
Resistance tolerance	%	50μΩ: ±3, ±5 100μΩ: ±2, ±5 >100μΩ: ±1, ±5			
TCR (resistive alloy)	ppm/°C	±10			
TCR (measurement)	ppm/°C	50μΩ: ±150 >50μΩ: ±100			
Standard values	μΩ	50, 100, 125, 200, 250			
Thermal EMF	μV/°C	<1			
Inductance (measurement)	nH	<5			
Ambient temperature range	°C	-65 to +170			

Physical Data Dimensions in mm and weight in g



Construction

A manganese alloy resistance element is e-beam welded between two copper terminations.

Marking

The components are unmarked.

Plating

The component can be supplied with or without Sn plating.

General Note

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Performance Data

Test	Method	±ΔR% max.
Load Life	1000 hours, cyclic load at Pr	1.0
Short Term Overload	5 seconds, 5 x Pr	1.0
High Temperature Exposure	1000 hours, +170°C	1.0
Temperature Cycle	1000 cycles, -55 to +150°C, 30 minute dwell	0.5
Low Temperature Storage	24 hours, -65°C	0.5
Biased Humidity	1000 hours, +85°C, 85%RH, 10% of Pr	0.5
Moisture Resistance	MIL-STD-202 Method 106, no load	0.5
Vibration	MIL-STD-202 Method 204, 5g for 20 mins, 12 cycles, 10-2000Hz	0.2
Mechanical Shock	MIL-STD-202 Method 213, 100g for 6ms, half sine	0.2
Resistance to Solder Heat	MIL-STD-202 Method 210, solder dip 260°C for 10s	0.5
Solderability	J-STD-002	95% coverage

Thermal Performance



Voltage Sense Terminal Style

Voltage sense terminal styles listed as Standard are available to order. Those marked Custom are examples of options which can be made available on request but may incur tooling charges.

Voltage Sance Terminal Ontion	Style	Figure	Availability	Pitch of Voltage Sense Points or Terminals in mm				
voltage sense rerminal Option	Style			50μΩ	100μΩ	125μΩ	200μΩ	250μΩ
No sense terminals	NT		Standard	7.7	12.2	13.5	19.7	24.2
Through hole Ø3.2mm	T2	1		10	14.5	15.9	21.9	26.4
Tapped hole M3 x 0.5	M3	2	Custom	10	14.5	15.9	21.9	26.4
Tapped hole M4 x 0.7	M4	2		11	15.5	16.9	22.9	27.4
"With dimple" location points	WD	3		10	14.5	15.9	21.9	26.4
Dowel fit pins	DF	4		10	14.5	15.9	21.9	26.4
Pressed pins	PP	5	Standard	7.7	12.2	13.5	19.7	24.2
Stress-relief pins	SP	6	Stanualu	7.7	12.2	13.5	19.7	24.2

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EBW8518

Voltage Sense Terminal Style

The centre-to-centre distance (pitch) of the voltage sense terminals varies with style and ohmic value and is shown in the table above. All dimensions are in mm.



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Packaging

Unplated EBW8518 shunts without voltage sense pins are supplied bulk packed in vacuum sealed plastic bags of 100 pieces. Plated parts without voltage sense pins may also be supplied in bulk but tray pack is standard. Parts with voltage sense terminal pins are tray packed.

Recommended Storage Conditions (packed):

Temperature 25°C to 35°C, humidity 30 to 80% RH.

Ordering Procedure

Example: EBW8518PNT-L050JT (50 micro-ohms ±5%, plated, no sense terminals, tray packed, Pb-free)

E B W	8 5 1 8	P N T	- L 0 5 0	JT
1	2	3 4	5	67

1	2	3	4	5		6	7		
Туре	Size	Finish	Sense Style	Value	То	lerance		ng	
EBW	8518	P = Sn Plated	NT = No terminals	L050 = 50μΩ	F = ±1%	(>100μΩ only)	Un-plated		B = Bulk
		U = Un-plated	PP = Pressed pins	L100 = 100μΩ	G = ±2%	(100μΩ only)	Distant	NT, T2, M3, M4, WD	B = Bulk (optional)
			SP = Stress-relief pin	L125 = 125μΩ	H = ±3%	(50μΩ only)	Plated		T = Tray (standard)
			Request availability	L200 = 200μΩ	J = ±5%	All values	Either finish	DF, PP, SP	T = Tray
			of custom styles	L250 = 250μΩ					

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